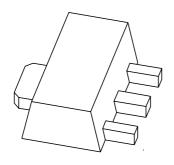
DISCRETE SEMICONDUCTORS

DATA SHEET



PXTA42 NPN high-voltage transistor

Product data sheet Supersedes data of 1999 Apr 26 2004 Dec 09



NPN high-voltage transistor

PXTA42

FEATURES

• Low current (max. 100 mA)

• High voltage (max. 300 V).

APPLICATIONS

• Telephony and professional communication equipment.

DESCRIPTION

NPN high-voltage transistor in a SOT89 plastic package. PNP complement: PXTA92.

MARKING

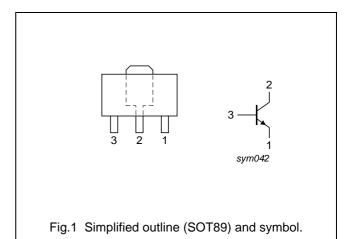
TYPE NUMBER	MARKING CODE ⁽¹⁾		
PXTA42	*1N		

Note

- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

PINNING

PIN	DESCRIPTION
1	emitter
2	collector
3	base



ORDERING INFORMATION

TYPE NUMBER		PACKAGE				
TIPE NOWIBER	NAME	NAME DESCRIPTION VE				
PXTA42	SC-62	plastic surface mounted package; collector pad for good heat transfer; 3 leads	SOT89			

NPN high-voltage transistor

PXTA42

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	300	V
V _{CEO}	collector-emitter voltage	open base	-	300	V
V _{EBO}	emitter-base voltage	open collector	_	6	V
I _C	collector current (DC)		-	100	mA
I _{CM}	peak collector current		-	200	mA
I _{BM}	peak base current		-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	-	1.3	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	ambient temperature		-65	+150	°C

Note

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	96	K/W
R _{th(j-s)}	thermal resistance from junction to soldering point		16	K/W

Note

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER CONDITIONS		MIN.	MAX.	UNIT	
I _{CBO}	collector-base cut-off current	I _E = 0 A; V _{CB} = 200 V	_	100	nA	
I _{EBO}	emitter-base cut-off current	I _C = 0 A; V _{BE} = 6 V	_	100	nA	
h _{FE}	DC current gain	I _C = 1 mA; V _{CE} = 10 V	25	_		
		I _C = 10 mA; V _{CE} = 10 V	40	_		
		$I_C = 30 \text{ mA}; V_{CE} = 10 \text{ V}$	40	_		
V _{CEsat}	collector-emitter saturation voltage	$I_C = 20 \text{ mA}; I_B = 2 \text{ mA}$	_	500	mV	
V _{BEsat}	base-emitter saturation voltage	$I_C = 20 \text{ mA}; I_B = 2 \text{ mA}$	_	900	mV	
C _{re}	feedback capacitance	$I_C = I_c = 0 \text{ A}; V_{CB} = 20 \text{ V};$ f = 1 MHz	_	3	pF	
f _T	transition frequency	I _C = 10 mA; V _{CE} = 20 V; f = 100 MHz	50	_	MHz	

^{1.} Device mounted on a printed-circuit board, single-sided copper, tin-plated, mounting pad for collector 6 cm². For other mounting conditions, see "Thermal considerations for SOT89 in the General Part of associated Handbook".

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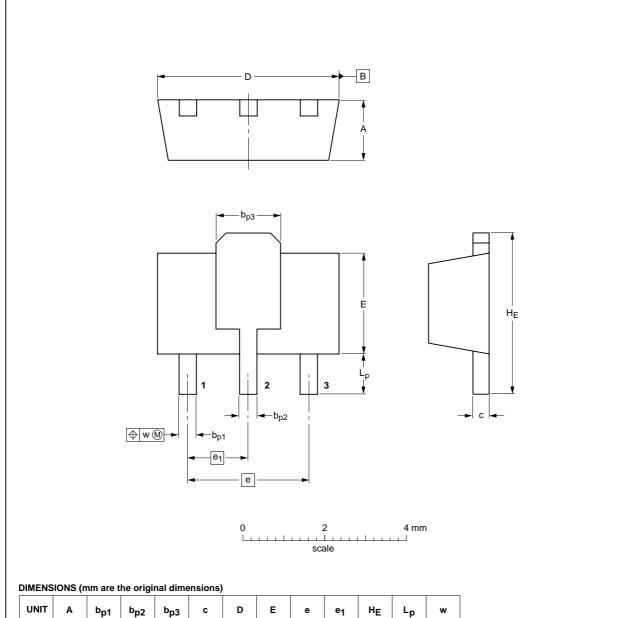
NPN high-voltage transistor

PXTA42

PACKAGE OUTLINE

Plastic surface-mounted package; collector pad for good heat transfer; 3 leads

SOT89



UNIT	A	b _{p1}	b _{p2}	b _{p3}	С	D	E	е	e ₁	HE	Lp	w
mm	1.6 1.4	0.48 0.35	0.53 0.40	1.8 1.4	0.44 0.23	4.6 4.4	2.6 2.4	3.0	1.5	4.25 3.75	1.2 0.8	0.13

OUTLINE		EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT89		TO-243	SC-62			04-08-03 06-03-16

NPN high-voltage transistor

PXTA42

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
- The product status of device(s) described in this document may have changed since this document was published
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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

For additional information please visit: http://www.nxp.com
For sales offices addresses send e-mail to: salesaddresses@nxp.com

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